

# isc N-Channel MOSFET Transistor

# AOD66406

### FEATURES

- Drain Current –I\_D= 60A@ T\_C=25 $^\circ\!\mathrm{C}$
- Drain Source Voltage-: V<sub>DSS</sub>=40V(Min)
- Static Drain-Source On-Resistance
  : R<sub>DS(on)</sub> =6.1m Ω (Max)
- 100% avalanche tested
- 100% avaianche testeu
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### DESCRIPTION

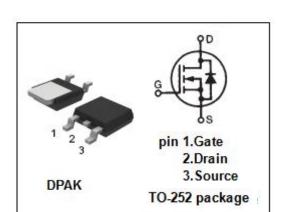
• Designed for use in switch mode power supplies and general purpose applications.

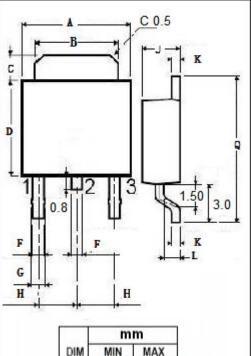
ABSOLUTE MAAIMOW RATINGS(Ta=25 C)						
SYMBOL	PARAMETER VALUE		UNIT			
V <sub>DSS</sub>	Drain-Source Voltage 40		V			
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±20	V			
ID	Drain Current-Continuous 60		А			
I <sub>DM</sub>	Drain Current-Single Pluse	150	A			
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25°C 52		W			
TJ	Max. Operating Junction Temperature	-55~150	°C			
T <sub>stg</sub>	Storage Temperature -55~150		°C			

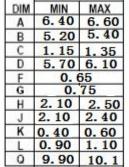
### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	2.4	°C/W







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### <sup>1</sup> *isc & iscsemi* is registered trademark



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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	40		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> = 0.25mA	1.5	2.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =20A V <sub>GS</sub> = 10V; I <sub>D</sub> =20A@T <sub>J</sub> =125℃		6.1 9.1	mΩ
lgss	Gate-Body Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0		±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =40V; V <sub>GS</sub> = 0 V <sub>DS</sub> =40V; V <sub>GS</sub> = 0@T <sub>J</sub> =55°C		1 5	μ <b>Α</b>
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 1A; V <sub>GS</sub> = 0		1	V



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